The RF MOSFET Line 45W, 150MHz, 28V

Technology Solutions

M/A-COM Products Released - Rev. 07.07

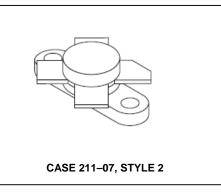
Designed primarily for wideband large–signal output and driver stages from **Product Image** 30–200 MHz.

N-Channel enhancement mode MOSFET

- Guaranteed performance at 150 MHz, 28 Vdc Output power = 45 W Power gain = 17 dB (min) Efficiency = 60% (min)
- Excellent thermal stability, ideally suited for Class A operation
- Facilitates manual gain control, ALC and modulation techniques
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Low Crss 8 pF @ VDS = 28 V
- Gold top metal

Typical data for power amplifier applications in industrial, commercial and amateur radio equipment

 Typical performance at 30 MHz, 28 Vdc Output power = 30 W (PEP) Power gain = 20 dB (typ.) Efficiency = 50% (typ.) IMD(d3) (30 W PEP) –32 dB (typ.)



MAXIMUM RATINGS

Rating	Symbol	Value		Unit	
Drain–Gate Voltage	VDSS	V _{DSS} 65		Vdc	
Drain–Gate Voltage (R _{GS} = 1.0 MΩ)		VDGR	6	5	Vdc
Gate-Source Voltage		VGS	±	20	Adc
Drain Current — Continuous		۱D	4	.5	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD		15 66	Watts W/°C	
Storage Temperature Range	T _{stg}	-65 to	o +150	°C	
Operating Junction Temperature	Tj	200		°C	
THERMAL CHARACTERISTICS					
Characteristic	Symbol	Max		Unit	
Thermal Resistance, Junction to Case	R ₀ JC	1.52		°C/W	
ELECTRICAL CHARACTERISTICS (T _C = 25°C unless	otherwise noted)				
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	-				
Drain–Source Breakdown Voltage (I _D = 50 mA, V _{GS} = 0)	V(BR)DSS	65	80	_	Vdc
Zero Gate Voltage Drain Current I _{DSS} (V _{GS} = 0, V _{DS} = 28 V)		-	_	1.0	mAdc
Gate-Source Leakage Current (V _{GS} = 20 V, V _{DS} = 0)	IGSS	—	—	1.0	μAdc

Gr

DQ

NOTE – <u>CAUTION</u> – MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling and packaging MOS devices should be observed.

- 1
- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

The RF MOSFET Line 45W, 150MHz, 28V

M/A-COM Products Released - Rev. 07.07

150MHz, 28V

ELECTRICAL CHARACTERISTICS – continued (T _C = 25	°C unless otherwise	e noted)				
Characteristic	Symbol	Min	Тур	Max	Unit	
ON CHARACTERISTICS						
Gate Threshold Voltage (V _{DS} = 10 V, I _D = 50 mA)	VGS(th)	1.5	2.5	4.5	Vdc	
Drain-Source On-Voltage (V _{GS} = 10 V, I _D = 3 A)	VDS(on)	-	1.0	-	V	
Forward Transconductance (V _{DS} = 10 V, I _D = 2 A)	9fs	1.4	1.8	-	mhos	
DYNAMIC CHARACTERISTICS						
Input Capacitance (V _{DS} = 28 V, V _{GS} = 0, f = 1.0 MHz)	C _{iss}	—	60	_	pF	
Output Capacitance (V _{DS} = 28 V, V _{GS} = 0, f = 1.0 MHz)	Coss	-	70	—	pF	
Reverse Transfer Capacitance (V _{DS} = 28 V, V _{GS} = 0, f = 1.0 MHz)	C _{rss}	-	8	—	pF	
FUNCTIONAL CHARACTERISTICS						
Common Source Power Gain (V _{DD} = 28 V, P _{out} = 45 W, f = 150 MHz, I _{DQ} = 25 mA)	Gps	17	19.5	_	dB	
Drain Efficiency (V _{DD} = 28 V, Pout = 45 W, f = 150 MHz, I _{DQ} = 25 mA)	η	60	70	_	%	
Electrical Ruggedness (V _{DD} = 28 V, P _{out} = 45 W, f = 150 MHz, I _{DQ} = 25 mA, VSWR 30:1 at All Phase Angles)		No Degradation in Output Power				
TYPICAL FUNCTIONAL TESTS (SSB)	-					
Common Source Power Gain (V _{DD} = 28 V, P _{out} = 30 W (PEP), I _{DQ} = 100 mA, f = 30; 30.001 MHz)	G _{ps}	-	20	_	dB	
Drain Efficiency (V _{DD} = 28 V, P _{out} = 30 W (PEP), I _{DQ} = 100 mA, f = 30; 30.001 MHz)	η	-	50	_	%	
Intermodulation Distortion (V _{DD} = 28 V, P _{out} = 30 W (PEP), I _{DQ} = 100 mA, f = 30; 30.001 MHz)	IMD(d3)	-	-32	_	dB	

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



R1

The RF MOSFET Line 45W, 150MHz, 28V



M/A-COM Products Released - Rev. 07.07

	$\xrightarrow{\text{BIAS}} \xrightarrow{R2} \xrightarrow{R3} \xrightarrow{L2} \xrightarrow{C6}$		$\begin{array}{c} RFC1 \\ \downarrow \\ C14 \\ \hline \\ C14 \\ \hline \\ C11 \\ \hline \\$
C1, C10 C2, C5, C8 C3 C4 C6, C14 C7 C9 C11, C12 C13 L1	1000 pF, Chip Capacitor 2–20 pF, Trimmer Capacitors, Johanson 43 pF, 100 mil Chip Capacitor, ATC 120 pF, 100 mil Chip Capacitor, ATC 0.1 μ F, Capacitors 50 pF, 100 mil Chip Capacitor, ATC 12 pF, 100 mil Chip Capacitor, ATC 680 pF, Feedthru Capacitors 50 μ F, 50 V, Electrolytic Capacitor 2 Turns, 0.297" ID, 18 AWG	R2 R3 Z1 Z2 Z3 Z4 Z5 Z6 Z7 RFC1 PFC2	1 kΩ, 1/2 W Chip Resistor 10 kΩ, 1/2 W Chip Resistor 0.160" \times 0.400" Microstrip 0.160" \times 0.600" Microstrip 0.160" \times 0.600" Microstrip 0.160" \times 0.900" Microstrip 0.160" \times 0.800" Microstrip 0.160" \times 0.800" Microstrip 0.160" \times 0.400" Microstrip 0.160" \times 0.400" Microstrip 0.160" \times 0.400" Microstrip Ferroxcube VK200–19/4B 10 Turne 0.VK200–19/4B
L2 L3 L4	1–1/2 Turns, 0.265″ ID, 18 AWG 1–1/4 Turns, 0.234″ ID, 18 AWG 1–1/2 Turns, 0.250″ ID, 18 AWG	RFC2 Board	10 Turns, 0.250″ ID, 20 AWG, Enamel 0.062″, G10 1 oz. Copper Clad Both Sides, $\varepsilon_{\rm F}$ = 2.56

68 Ω, 1/2 W Chip Resistor

Figure 1. MRF171A 150 MHz Test Circuit

3

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product W/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 ٠ Visit www.macomtech.com for additional data sheets and product information.

The RF MOSFET Line 45W, 150MHz, 28V



M/A-COM Products Released - Rev. 07.07

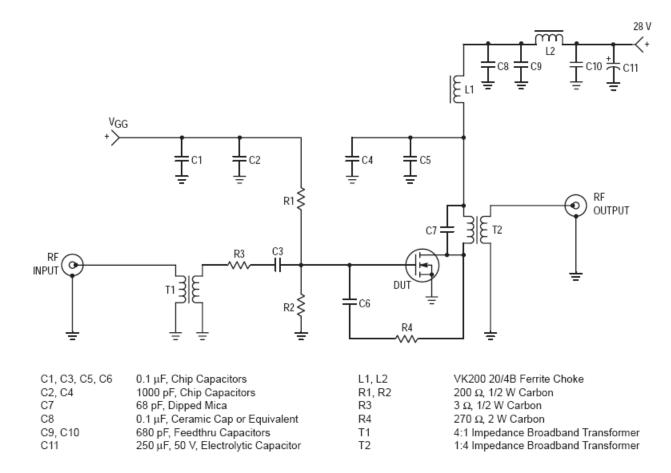


Figure 2. MRF171A 30 MHz Test Circuit

4

- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

The RF MOSFET Line 45W, 150MHz, 28V



M/A-COM Products Released - Rev. 07.07

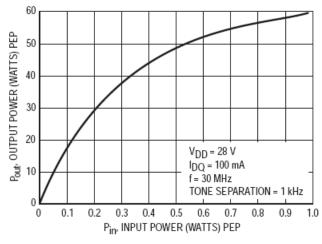


Figure 3. Output Power versus Input Power

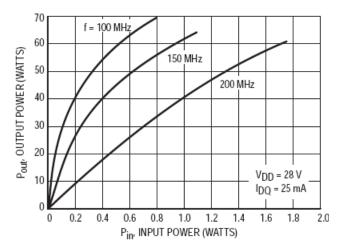


Figure 4. Output Power versus Input Power

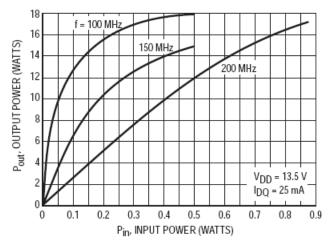


Figure 5. Output Power versus Input Power

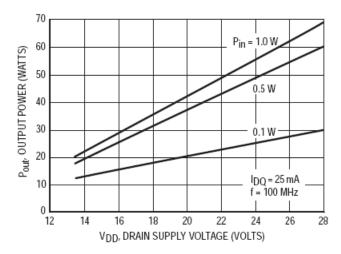


Figure 6. Output Power versus Supply Voltage

- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

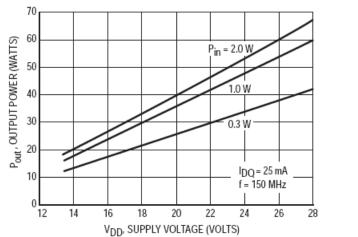
M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

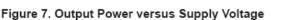
TYPICAL CHARACTERISTICS

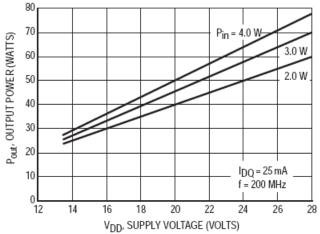


The RF MOSFET Line 45W, 150MHz, 28V

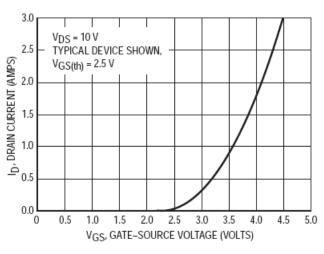
M/A-COM Products Released - Rev. 07.07

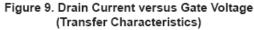






bly Voltage Figure 8. Output Power versus Supply Voltage





TYPICAL CHARACTERISTICS

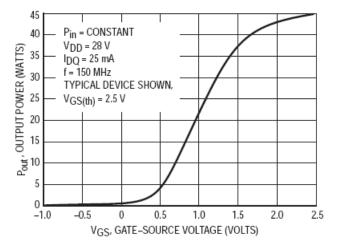


Figure 10. Output Power versus Gate Voltage

- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

The RF MOSFET Line 45W, 150MHz, 28V



M/A-COM Products Released - Rev. 07.07

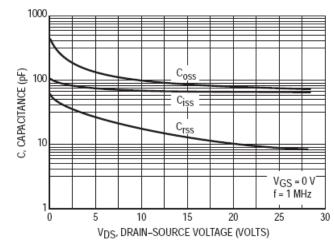


Figure 11. Capacitance versus Drain-Source Voltage

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY**: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

7

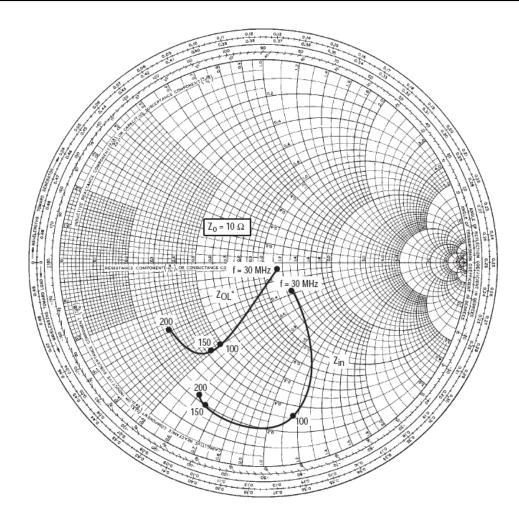
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

The RF MOSFET Line 45W, 150MHz, 28V



M/A-COM Products Released - Rev. 07.07



V _{DD} = 28 V, I _{DQ} = 25 mA, P _{out} = 45 W									
f MHz	Z _{in} (1) Ω	Z _{OL} (2) Ω							
30	12.8 – j3.6	11.5 – j0.99							
100	3.1 – j11.6	4.9 – j4.9							
150	2.0 – j6.5	4.2 – j4.9							
200	2.2 – j6.0	3.0 – j2.9							

(1) 68 Ω shunt resistor gate-to-ground.

(2) Z_{OL} = Conjugate of the optimum load impedance into which the device operates at a given output power, voltage and frequency.

Figure 12. Large-Signal Series Equivalent Input/Output Impedance

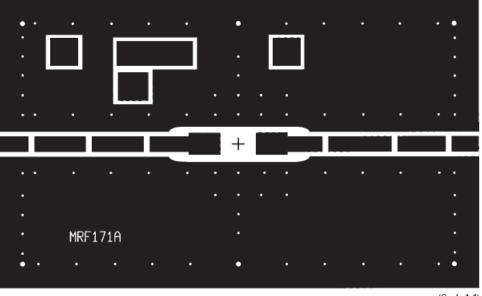
ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.





M/A-COM Products Released - Rev. 07.07



(Scale 1:1)

Figure 13. MRF171A Circuit Board Photo Master

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY**: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

9

- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266



The RF MOSFET Line 45W, 150MHz, 28V

M/A-COM Products

Released - Rev. 07.07

Table 1. Common Source S–Parameters (V _{DS} = 12.5 V, I _D = 0.5 A)											
f	\$ ₁₁		\$ ₂₁		\$ ₁₂		S	22			
MHz	\$ ₁₁	φ	\$ ₂₁	φ	\$ ₁₂	φ	\$ ₂₂	φ			
30	0.801	-162	11.90	96	0.026	13	0.811	-166			
40	0.809	-166	9.12	91	0.028	11	0.812	-171			
50	0.810	-169	7.29	88	0.027	11	0.831	-172			
60	0.808	-170	6.22	85	0.028	9	0.824	-174			
70	0.814	-172	5.30	82	0.028	9	0.831	-176			
80	0.811	-173	4.56	81	0.027	10	0.837	-175			
90	0.811	-174	4.04	80	0.027	13	0.829	-174			
100	0.814	-174	3.66	77	0.027	12	0.846	-176			
110	0.812	-175	3.37	75	0.027	11	0.842	-177			
120	0.816	-175	3.00	74	0.027	13	0.850	-176			
130	0.816	-176	2.75	73	0.027	14	0.849	-175			
140	0.817	-176	2.57	72	0.027	17	0.851	-176			
150	0.821	-176	2.37	69	0.027	17	0.863	-177			
160	0.820	-176	2.27	67	0.027	17	0.853	-177			
170	0.821	-177	2.08	66	0.026	19	0.838	-177			
180	0.824	-177	1.93	65	0.027	19	0.861	-177			
190	0.825	-177	1.89	64	0.027	21	0.873	-177			
200	0.830	-177	1.74	62	0.027	23	0.873	-178			
210	0.831	-177	1.67	60	0.027	25	0.874	-177			
220	0.831	-178	1.62	59	0.026	28	0.870	-178			
230	0.836	-178	1.48	57	0.027	27	0.909	-179			
240	0.836	-178	1.43	56	0.027	26	0.865	-180			
250	0.839	-178	1.37	57	0.028	30	0.873	-178			
260	0.844	-178	1.30	54	0.028	34	0.882	-179			
270	0.842	-178	1.28	52	0.028	36	0.887	-180			
280	0.845	-179	1.21	52	0.027	37	0.881	-180			
290	0.849	-179	1.14	50	0.027	36	0.869	179			
300	0.849	-179	1.12	50	0.029	39	0.852	-180			
310	0.855	-179	1.06	49	0.029	42	0.891	-179			
320	0.856	-179	1.03	46	0.030	43	0.889	180			
330	0.856	-180	0.96	45	0.031	47	0.868	180			
340	0.858	-180	0.96	46	0.030	47	0.888	179			
350	0.860	180	0.93	44	0.031	49	0.875	-180			
360	0.862	180	0.91	44	0.033	48	0.901	179			
370	0.866	180	0.86	43	0.034	50	0.913	178			
380	0.867	179	0.84	41	0.036	52	0.897	178			
390	0.869	179	0.82	42	0.035	54	0.893	178			
400	0.870	179	0.78	40	0.035	57	0.880	180			
410	0.872	179	0.77	39	0.037	55	0.923	178			
420	0.876	178	0.73	37	0.039	54	0.915	176			
430	0.877	178	0.69	38	0.040	56	0.903	177			
440	0.879	178	0.68	39	0.041	58	0.921	178			

Table 1. Common Source S-Parameters (VDS = 12.5 V, ID = 0.5 A)

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology • North America Tel: 800.366.2266 / Fax: 978.366.2266

• Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

• Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

Visit www.macomtech.com for additional data sheets and product information.

Asia/Pacific T
 PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology
 Solutions has under development. Performance is based on engineering tests. Specifications are
 typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.
 MA-COM Technology
 changes to the produce





M/A-COM Products Released - Rev. 07.07

f	\$ ₁₁		\$ ₂₁		\$ ₁₂		\$ ₂₂			
MHz	\$ ₁₁	φ	\$ ₂₁	φ	\$ ₁₂	φ	\$ ₂₂	φ		
450	0.882	177	0.68	36	0.040	61	0.926	178		
460	0.884	177	0.65	36	0.041	59	0.937	175		
470	0.886	177	0.62	35	0.041	60	0.896	176		
480	0.885	176	0.62	33	0.044	61	0.907	176		
490	0.886	176	0.61	32	0.046	63	0.907	176		
500	0.887	176	0.59	31	0.047	65	0.916	175		

Table 1. Common Source S-Parameters (VDS = 12.5 V, ID = 0.5 A) (continued)

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

11

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



The RF MOSFET Line 45W, 150MHz, 28V

M/A-COM Products

Released - Rev. 07.07

	Table 2. Common Source S–Parameters (V_{DS} = 28 V, I_{D} = 0.5 A)										
f MHz	\$ ₁₁	φ	\$ ₂₁	φ	\$ ₁₂	φ	S ₂₂	φ			
30	0.783	-152	17.10	100	0.025	17	0.730	-158			
40	0.793	-158	13.20	94	0.027	13	0.730	-164			
50	0.793	-162	10.50	90	0.027	12	0.754	-167			
60	0.791	-165	9.00	87	0.027	11	0.746	-169			
70	0.798	-167	7.68	83	0.026	10	0.760	-171			
80	0.795	-169	6.63	82	0.026	10	0.770	-170			
90	0.795	-170	5.85	80	0.026	12	0.760	-170			
100	0.799	-170	5.30	77	0.026	10	0.779	-172			
110	0.798	-171	4.86	75	0.026	11	0.775	-174			
120	0.802	-172	4.35	74	0.025	13	0.785	-172			
130	0.801	-172	3.97	72	0.025	14	0.788	-171			
140	0.803	-173	3.70	71	0.025	15	0.791	-172			
150	0.809	-173	3.42	68	0.025	14	0.808	-173			
160	0.808	-173	3.27	66	0.025	15	0.796	-172			
170	0.809	-174	2.99	65	0.024	18	0.783	-174			
180	0.814	-174	2.77	63	0.025	19	0.809	-173			
190	0.815	-175	2.71	62	0.024	21	0.820	-174			
200	0.822	-175	2.49	60	0.024	22	0.826	-175			
210	0.824	-175	2.37	57	0.024	24	0.836	-175			
220	0.825	-175	2.23	57	0.024	26	0.807	-175			
230	0.831	-176	2.08	56	0.024	29	0.839	-175			
240	0.830	-176	2.00	54	0.024	29	0.818	-176			
250	0.832	-176	1.92	55	0.024	33	0.828	-174			
260	0.838	-176	1.81	53	0.024	35	0.829	-175			
270	0.837	-176	1.79	50	0.025	37	0.834	-175			
280	0.840	-177	1.69	50	0.025	39	0.832	-176			
290	0.844	-177	1.60	48	0.025	39	0.836	-177			
300	0.844	-177	1.55	48	0.025	44	0.814	-175			
310	0.849	-178	1.48	47	0.026	46	0.848	-175			
320	0.852	-178	1.43	44	0.027	45	0.855	-177			
330	0.852	-178	1.35	43	0.028	48	0.833	-177			
340	0.855	-178	1.32	44	0.028	49	0.861	-177			
350	0.856	-178	1.29	41	0.029	53	0.842	-176			

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology • North America Tel: 800.366.2266 / Fax: 978.366.2266

• Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

PRELIMINARY: Data Sheets contain information regarding a product W/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.



M/A-COM Products Released - Rev. 07.07

	Table 2. Common Source S–Parameters (V_{DS} = 28 V, I_{D} = 0.5 A) (continued)										
f MHz	\$ ₁₁	φ	\$ ₂₁	φ	\$ ₁₂	φ	\$ ₂₂	φ			
360	0.859	-179	1.25	42	0.030	54	0.872	-178			
370	0.863	-179	1.18	39	0.030	55	0.886	-178			
380	0.864	-179	1.15	38	0.031	55	0.864	-178			
390	0.867	-179	1.12	39	0.032	57	0.862	-179			
400	0.869	-180	1.07	37	0.032	60	0.853	-177			
410	0.872	-180	1.05	35	0.035	60	0.898	-179			
420	0.876	180	1.00	34	0.036	60	0.889	180			
430	0.877	179	0.95	35	0.037	62	0.884	-179			
440	0.879	179	0.93	34	0.038	64	0.902	-179			
450	0.882	179	0.91	32	0.039	65	0.901	-180			
460	0.884	178	0.88	32	0.041	64	0.922	179			
470	0.885	178	0.84	32	0.040	66	0.877	179			
480	0.885	178	0.83	30	0.042	66	0.892	179			
490	0.886	177	0.81	29	0.044	68	0.891	179			
500	0.887	177	0.80	28	0.045	68	0.900	178			

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product W/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

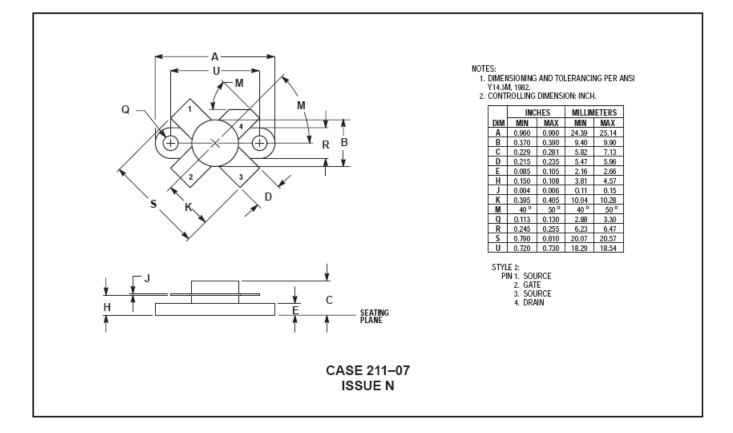
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 ٠ Visit www.macomtech.com for additional data sheets and product information.





M/A-COM Products Released - Rev. 07.07

PACKAGE DIMENSIONS



14

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266





Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.З, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж: moschip.ru moschip.ru_4

moschip.ru_6 moschip.ru_9